



SANYO Semiconductors

DATA SHEET

ECH8306 — P-Channel Silicon MOSFET

General-Purpose Switching Device Applications

Features

- Low ON-resistance.
- 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|------------------|--|-------------|------|
| Drain-to-Source Voltage | V _{DSS} | | -100 | V |
| Gate-to-Source Voltage | V _{GSS} | | ±20 | V |
| Drain Current (DC) | I _D | | -2 | A |
| Drain Current (Pulse) | I _{DP} | PW≤10μs, duty cycle≤1% | -12 | A |
| Allowable Power Dissipation | P _D | Mounted on a ceramic board (900mm ² ×0.8mm) | 1.6 | W |
| Channel Temperature | T _{ch} | | 150 | °C |
| Storage Temperature | T _{stg} | | -55 to +150 | °C |

Electrical Characteristics at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--|----------------------|---|---------|------|------|------|
| | | | min | typ | max | |
| Drain-to-Source Breakdown Voltage | V _{(BR)DSS} | I _D =-1mA, V _{GS} =0V | -100 | | | V |
| Zero-Gate Voltage Drain Current | I _{DSS} | V _{DS} =-100V, V _{GS} =0V | | | -1 | μA |
| Gate-to-Source Leakage Current | I _{GSS} | V _{GS} =±16V, V _{DS} =0V | | | ±10 | μA |
| Cutoff Voltage | V _{GS(off)} | V _{DS} =-10V, I _D =-1mA | -1.2 | | -2.6 | V |
| Forward Transfer Admittance | y _{fs} | V _{DS} =-10V, I _D =-1A | 2.9 | 4.9 | | S |
| Static Drain-to-Source On-State Resistance | R _{DS(on)1} | I _D =-1A, V _{GS} =-10V | | 170 | 225 | mΩ |
| | R _{DS(on)2} | I _D =-0.5A, V _{GS} =-4V | | 195 | 275 | mΩ |
| Input Capacitance | C _{iss} | V _{DS} =-20V, f=1MHz | | 1600 | | pF |
| Output Capacitance | C _{oss} | V _{DS} =-20V, f=1MHz | | 85 | | pF |
| Reverse Transfer Capacitance | C _{rss} | V _{DS} =-20V, f=1MHz | | 72 | | pF |
| Turn-ON Delay Time | t _{d(on)} | See specified Test Circuit. | | 13.5 | | ns |
| Rise Time | t _r | See specified Test Circuit. | | 10 | | ns |
| Turn-OFF Delay Time | t _{d(off)} | See specified Test Circuit. | | 190 | | ns |
| Fall Time | t _f | See specified Test Circuit. | | 54 | | ns |
| Total Gate Charge | Q _g | V _{DS} =-50V, V _{GS} =-10V, I _D =-2A | | 33 | | nC |
| Gate-to-Source Charge | Q _{gs} | V _{DS} =-50V, V _{GS} =-10V, I _D =-2A | | 3.6 | | nC |
| Gate-to-Drain "Miller" Charge | Q _{gd} | V _{DS} =-50V, V _{GS} =-10V, I _D =-2A | | 6.0 | | nC |
| Diode Forward Voltage | V _{SD} | I _S =-2A, V _{GS} =0V | | -0.8 | -1.2 | V |

Marking : JH

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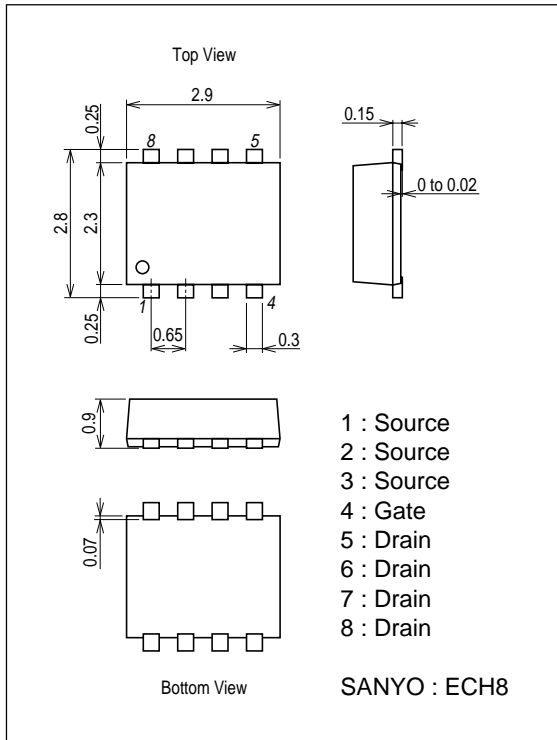
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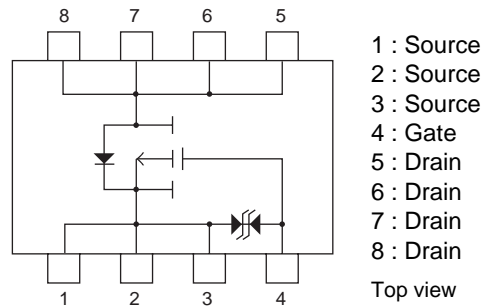
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Package Dimensions

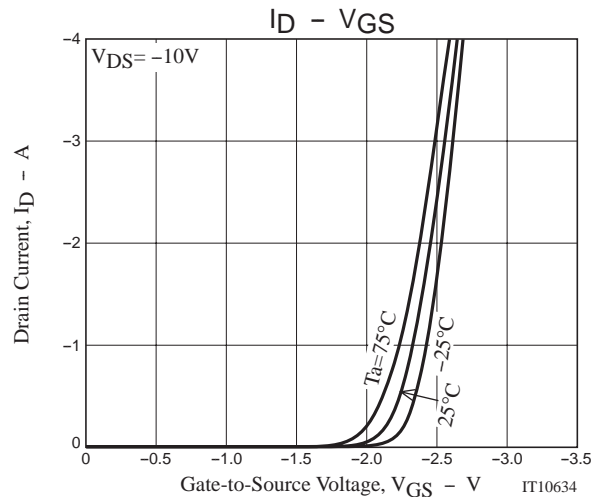
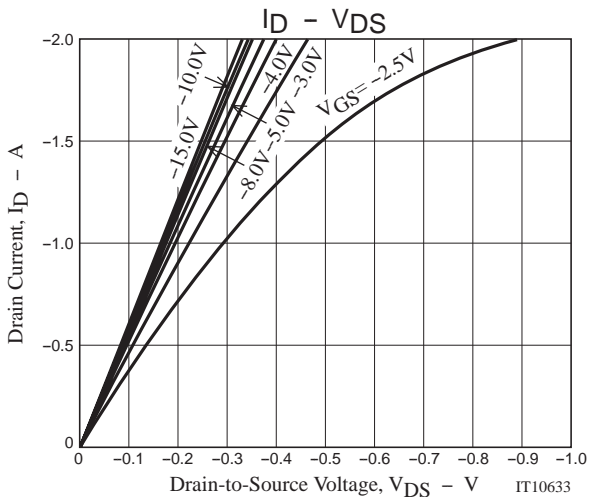
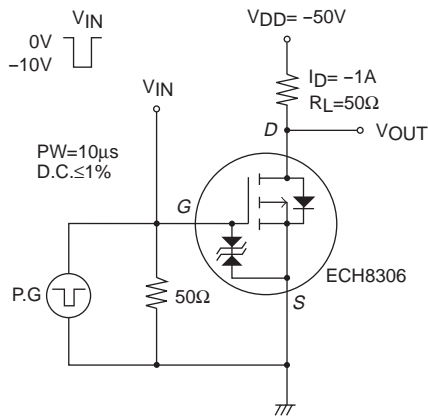
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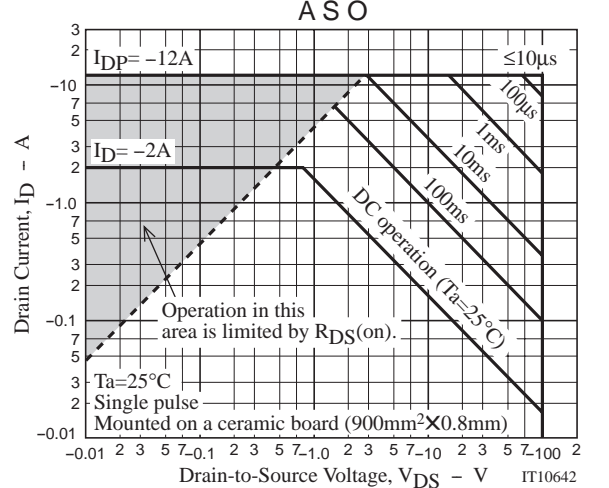
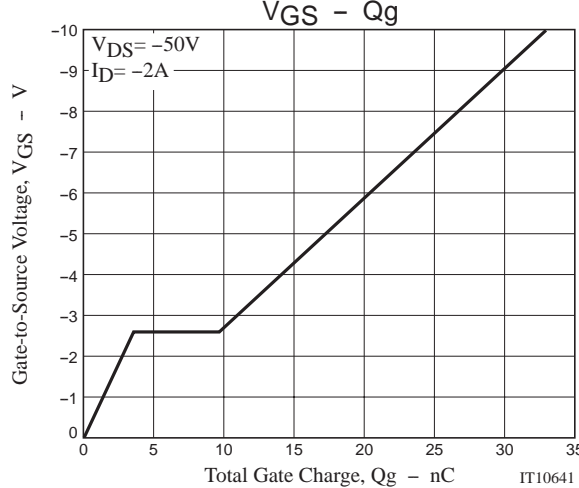
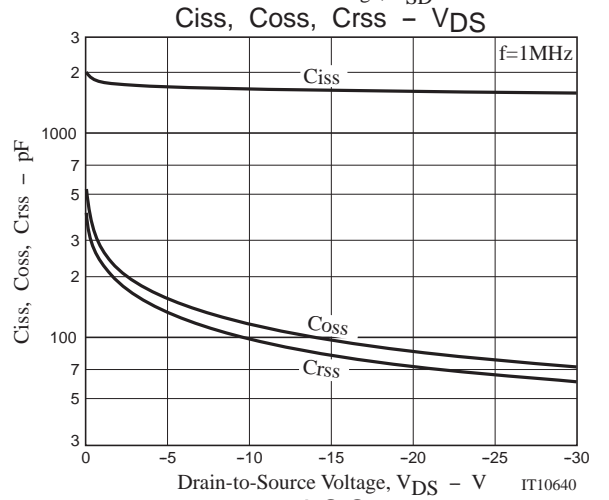
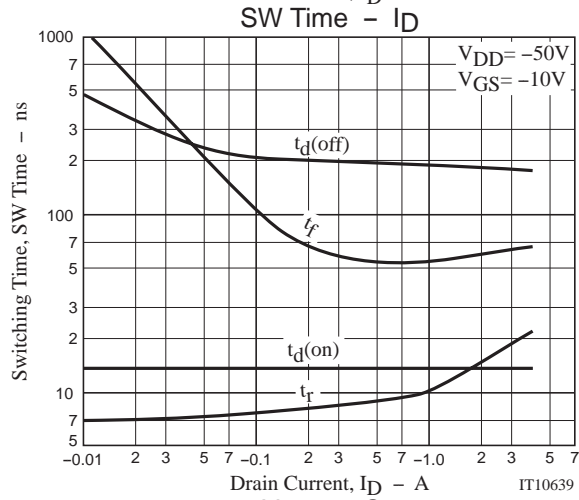
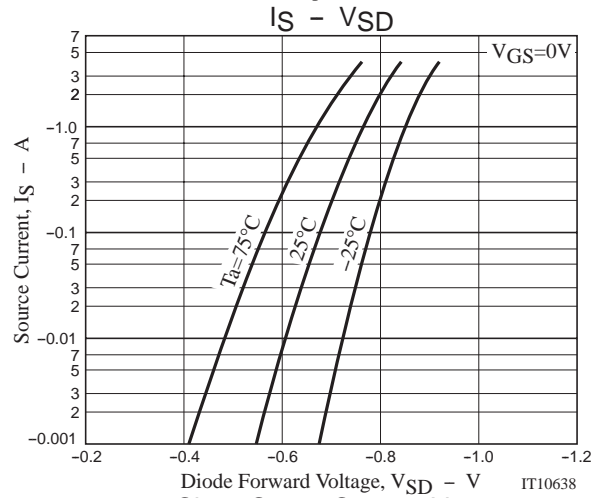
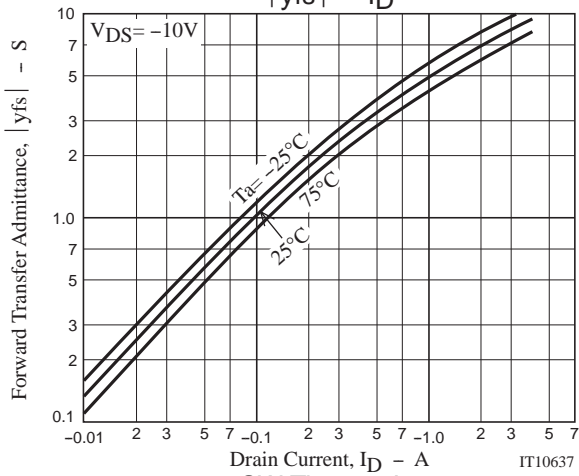
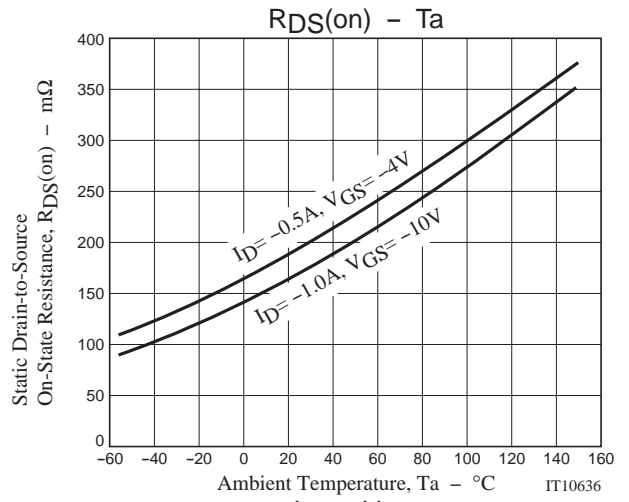
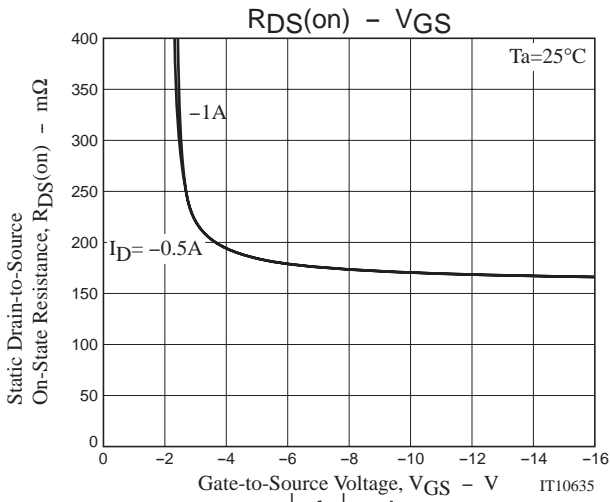


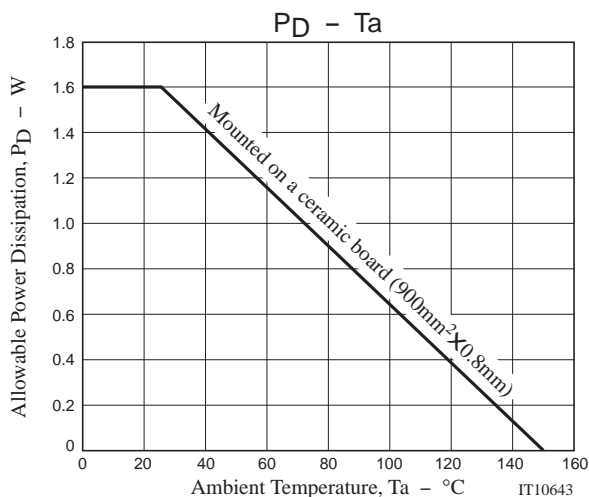
Electrical Connection



Switching Time Test Circuit







Note on usage : Since the ECH8306 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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